

# Li Xinyu

## List of Publications by Year in descending order

Source: <https://exaly.com/author-pdf/1941184/publications.pdf>

Version: 2024-02-01

4  
papers

32  
citations

2258059

3  
h-index

2272923

4  
g-index

4  
all docs

4  
docs citations

4  
times ranked

26  
citing authors

#	ARTICLE	IF	CITATIONS
1	Degradation in super-junction MOSFET under successive exposure of heavy ion strike and gamma ray irradiation. <i>Microelectronics Reliability</i> , 2022, 132, 114529.	1.7	2
2	A Novel Split-Gate-Trench MOSFET Integrated With Normal Gate and Built-In Channel Diode. <i>IEEE Journal of the Electron Devices Society</i> , 2021, 9, 839-845.	2.1	4
3	Gate Oxide Damage of SiC MOSFETs Induced by Heavy-Ion Strike. <i>IEEE Transactions on Electron Devices</i> , 2021, 68, 4010-4015.	3.0	11
4	Degradation of Radiation-Hardened Vertical Double-Diffused Metal-Oxide-Semiconductor Field-Effect Transistor During Gamma Ray Irradiation Performed After Heavy Ion Striking. <i>IEEE Electron Device Letters</i> , 2020, 41, 216-219.	3.9	15